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Thyristor High Voltage, Phase Control SCR, 30 A



PRIMARY CHARACTERISTICS			
I _{T(AV)}	20 A		
V _{DRM} /V _{RRM}	1200 V		
V _{TM}	1.3 V		
I _{GT}	45 mA		
TJ	-40 °C to +125 °C		
Package	TO-247AD 3L		
Circuit configuration	Single SCR		

FEATURES

- Designed and qualified according to PS JEDEC[®] - JESD 47

 RoHS
- Flexible solution for reliable AC power COMPLIANT rectification
 FREE
- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

• Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-30TPS12L-M3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. AEC-Q101 qualified P/N available (VS-30TPS12LHM3).

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{T(AV)}	Sinusoidal waveform	20	А	
I _{RMS}		30	^	
V _{RRM} /V _{DRM}		1200	V	
I _{TSM}		300	А	
V _T	20 A, T _J = 25 °C	1.3	V	
dv/dt		500	V/µs	
di/dt		150	A/µs	
TJ		-40 to +125	°C	

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
VS-30TPS12L-M3	1200	1300	10

VS-30TPS12L-M3



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PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 95 °C, 180° conduction	half sine wave	20	
Maximum RMS on-state current	I _{RMS}			30	^
Maximum peak, one-cycle		10 ms sine pulse, rated V_{RRM}	applied	250	A
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage	reapplied	300	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM}	applied	310	A ² s
Maximum -t for fusing	1-1	10 ms sine pulse, no voltage reapplied		442	A-2
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied		4420	A²√s
Maximum on-state voltage drop	V _{TM}	20 A, T _J = 25 °C		1.3	V
On-state slope resistance	r _t	T 105 %C		12	mΩ
Threshold voltage	V _{T(TO)}	- T _J = 125 °C		1.0	V
Maximum reverse and direct leakage	1 /1	T _J = 25 °C	V reted V /V	0.5	
current	I _{RM} /I _{DM}	$T_J = 125 \degree C$ $V_R = rated V_{RRM} / V_{DRM}$		10	mA
Maximum holding current	Ι _Η	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		150	ША
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25 \degree C$		200	
Maximum rate of rise of off-state voltage	dv/dt	$T_J = T_J$ maximum, linear to 80 % V _{DRM} , R_g -k = open		500	V/µs
Maximum rate of rise of turned-on current	di/dt			150	A∕µs

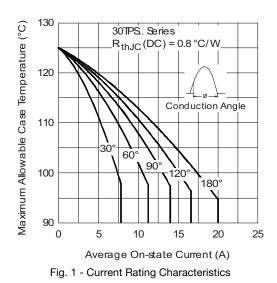
TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P _{GM}		8.0	W	
Maximum average gate power	P _{G(AV)}		2.0	vv	
Maximum peak positive gate current	+I _{GM}		1.5	А	
Maximum peak negative gate voltage	-V _{GM}		10	V	
	I _{GT}	Anode supply = 6 V, resistive load, $T_J = -10 \ ^{\circ}C$	60	mA	
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$	45		
		Anode supply = 6 V, resistive load, $T_J = 125 \text{ °C}$	20		
		Anode supply = 6 V, resistive load, $T_J = -10 \ ^{\circ}C$	2.5		
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$	2.0	v	
		Anode supply = 6 V, resistive load, $T_J = 125 \text{ °C}$	1.0	v	
Maximum DC gate voltage not to trigger V _{GD}			0.25		
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = rated value	2.0	mA	

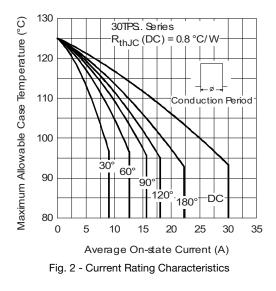
SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T.I = 125 °C	4	μs
Typical turn-off time	t _q	ij = 123 0	110	



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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS
Maximum junction and st temperature range	torage	T _J , T _{Stg}		-40 to 125	°C
Maximum thermal resista junction to case	ince,	R _{thJC}	DC operation	0.8	
Maximum thermal resista junction to ambient	ince,	R _{thJA}		40	°C/W
Maximum thermal resista case to heatsink	ince,	R _{thCS}	Mounting surface, smooth and greased 0.25		
Approximate weight	A			6	g
				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm
would in good	maximum			12 (10)	(lbf ⋅ in)
Marking device	Marking device Case style TO-247AD 3L 30TPS		S12L		





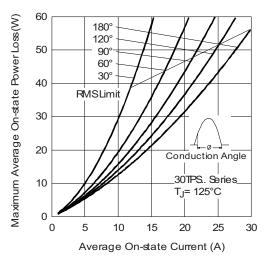
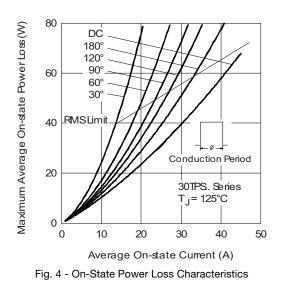


Fig. 3 - On-State Power Loss Characteristics



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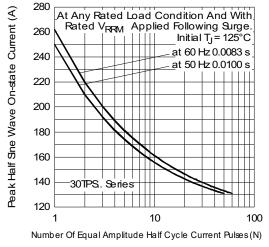
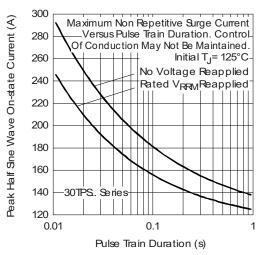
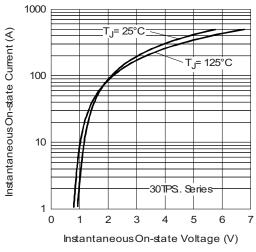
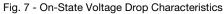


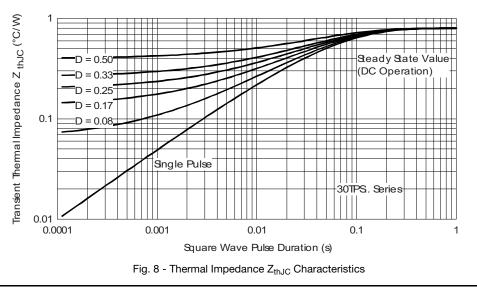
Fig. 5 - Maximum Non-Repetitive Surge Current











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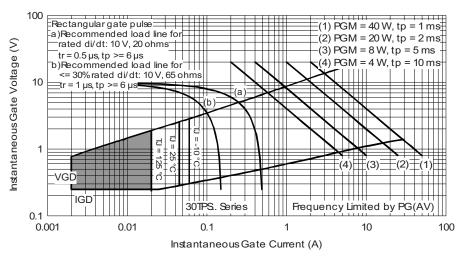
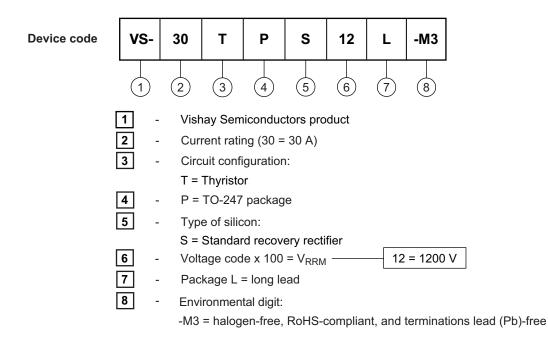


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-30TPS12L-M3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS					
Dimensions TO-247AD 3L www.vishay.com/doc?95626					
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007			

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